

## ADD-A-PAK Generation VII Power Modules Schottky Rectifier, 110 A



ADD-A-PAK

PRODUCT SUMMARY	
$I_{F(AV)}$	110 A
$V_R$	30 V
Package	ADD-A-PAK
Circuit	Two diodes doubler circuit

### MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### FEATURES

- 150 °C  $T_J$  operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT

### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

### ELECTRICAL DESCRIPTION

The VS-VSKDS220.. Schottky rectifier doubler has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	110	A
$V_{RRM}$		30	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	18 000	A
$V_F$	110 A <sub>pk</sub> , $T_J = 125 \text{ }^\circ\text{C}$	0.57	V
$T_J$	Range	- 55 to 150	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-VSKDS220/030	UNITS
Maximum DC reverse voltage	$V_R$	30	V
Maximum working peak reverse voltage	$V_{RWM}$		



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at $T_C = 110\text{ }^\circ\text{C}$ , rectangular waveform		110	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	5 $\mu\text{s}$ sine or 3 $\mu\text{s}$ rect. pulse	Following any rated load condition and with rated $V_{RRM}$ applied	18 000	
		10 ms sine or 6 ms rect. pulse		2000	
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25\text{ }^\circ\text{C}$ , $I_{AS} = 15\text{ A}$ , $L = 1\text{ mH}$		99	mJ
Repetitive avalanche current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu\text{s}$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical		22	A

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	110 A	$T_J = 25\text{ }^\circ\text{C}$	0.59	V
		220 A		0.78	
		110 A	$T_J = 125\text{ }^\circ\text{C}$	0.57	
		220 A		0.82	
Maximum reverse leakage current	$I_{RM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{Rated } V_R$	10	mA
		$T_J = 125\text{ }^\circ\text{C}$		650	
Maximum junction capacitance	$C_T$	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^\circ\text{C}$		7400	pF
Typical series inductance	$L_S$	Measured lead to lead 5 mm from package body		7.0	nH
Maximum voltage rate of change	dV/dt	Rated $V_R$		10 000	V/ $\mu\text{s}$
Maximum RMS insulation voltage	$V_{INS}$	50 Hz		3000 (1 min)	V
				3600 (1 s)	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum junction and storage temperature range	$T_J, T_{Stg}$			- 55 to 150	$^\circ\text{C}$	
Maximum thermal resistance, junction to case per leg	$R_{thJC}$	DC operation		0.52	$^\circ\text{C/W}$	
Typical thermal resistance, case to heatsink per module	$R_{thCS}$			0.1		
Approximate weight					75	g
					2.7	oz.
Mounting torque $\pm 10\%$	to heatsink	A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the spread of the compound.		4	Nm	
	busbar			3		
Case style		JEDEC <sup>®</sup>		TO-240AA compatible		

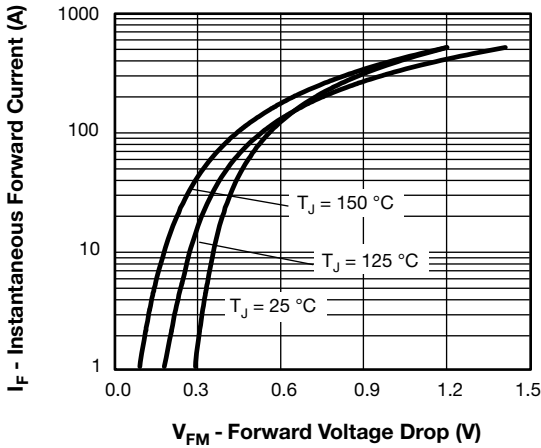


Fig. 1 - Maximum Forward Voltage Drop Characteristics

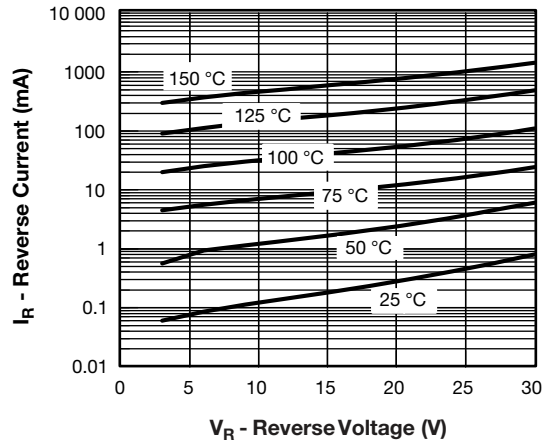


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

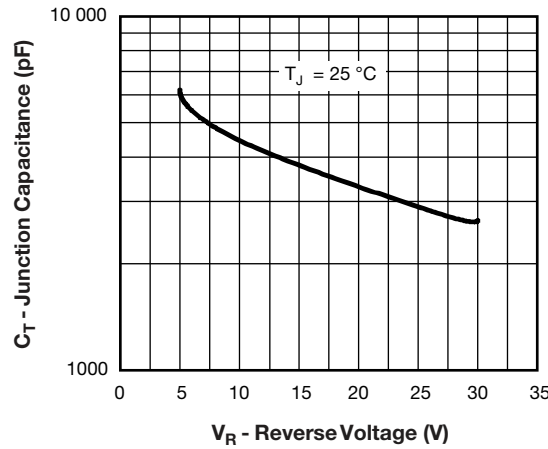


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

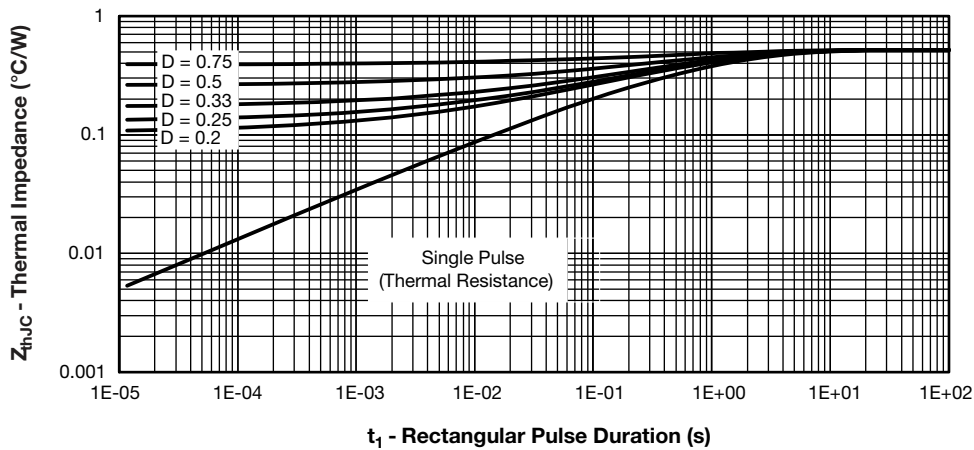


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

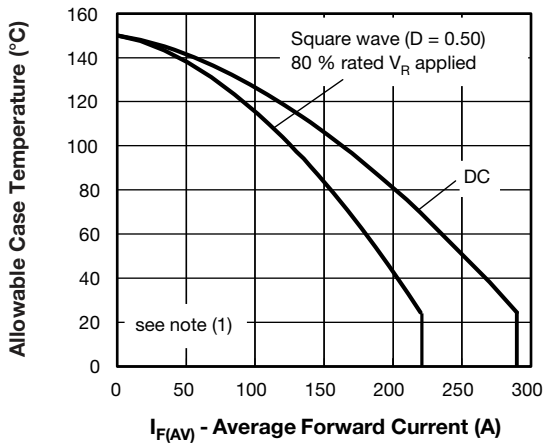


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

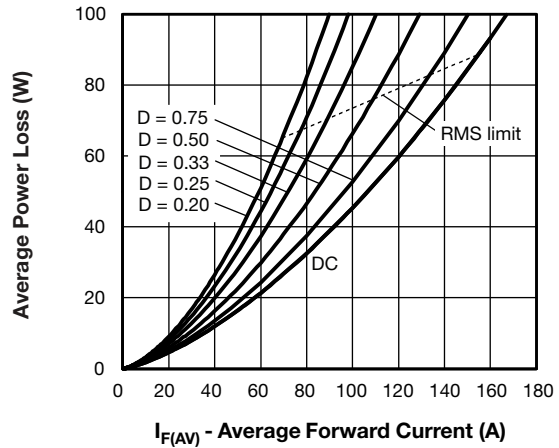


Fig. 6 - Forward Power Loss Characteristics

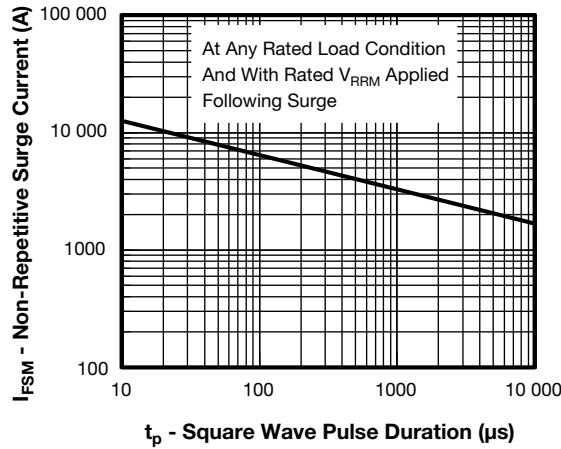


Fig. 7 - Maximum Non-Repetitive Surge Current

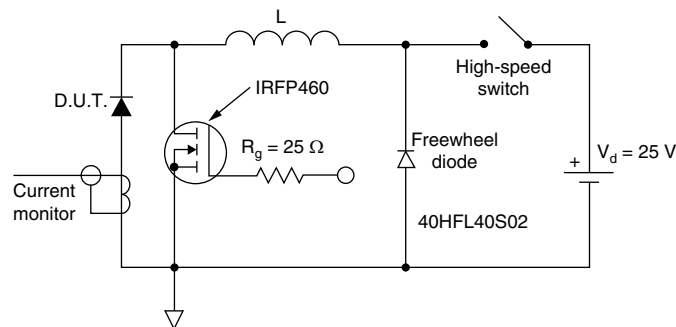


Fig. 8 - Unclamped Inductive Test Circuit

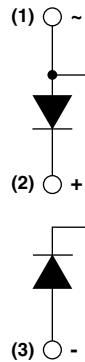
**Note**

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = Forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $P_{dREV}$  = Inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$

**ORDERING INFORMATION TABLE**

Device code	<b>VS-VS</b>	<b>KD</b>	<b>S</b>	<b>22</b>	<b>0</b>	<b>/</b>	<b>030</b>
	①	②	③	④	⑤		⑥

- 1** - VS-VS = Vishay Semiconductors product
- 2** - Circuit configuration:  
KD = ADD-A-PAK - 2 diodes in series
- 3** - S = Schottky diode
- 4** - Average rating (x 10)
- 5** - Product silicon identification
- 6** - Voltage rating (030 = 30 V)

**CIRCUIT CONFIGURATION**

**LINKS TO RELATED DOCUMENTS**

Dimensions	<a href="http://www.vishay.com/doc?95369">www.vishay.com/doc?95369</a>
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## ADD-A-PAK Generation VII - Diode

**DIMENSIONS** in millimeters (inches)





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